

Description

The DIODES™ PAM2861 is a continuous mode inductive step-down converter, designed for driving single or multiple series connected LEDs efficiently from a voltage source higher than the LED voltage. The device operates from an input supply between 6V and 40V and provides an externally adjustable output current of up to 1A. Depending upon supply voltage and external components, this can provide up to 30 watts of output power.

The PAM2861 includes the output switch and a high-side output current sensing circuit, which uses an external resistor to set the nominal average output current.

Output current can be adjusted below the set value, by applying an external control signal to the VSET pin.

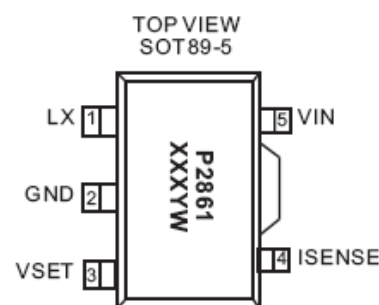
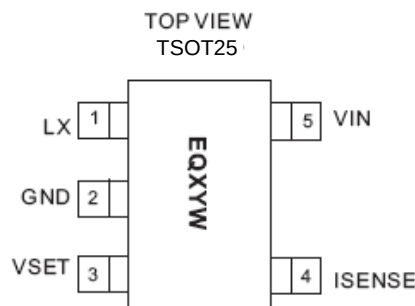
The VSET pin will accept either a DC voltage or a PWM waveform.

The soft-start time can be increased using an external capacitor from the VSET pin to ground. Applying a voltage of 0.2V or lower to the VSET pin turns the output off and switches the device into a low current standby state.

Features

- Simple Low Parts Count
- Internal 40V NDMOS Switch
- 1A Output Current
- Single Pin On/Off and Brightness Control Using DC Voltage or PWM
- Soft-Start
- High Efficiency (Up to 97%)
- Wide Input Voltage Range: 6V to 40V
- Output Shutdown
- Open LED Protection
- Short LED Protection
- Up to 1MHz Switching Frequency
- Inherent Open-Circuit LED Protection
- Typical 5% Output Current Accuracy
- Pb-Free TSOT25 and SOT89-5 Packages
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](mailto:sales@diodes.com) or your local Diodes representative.**
<https://www.diodes.com/quality/product-definitions/>

Pin Assignments



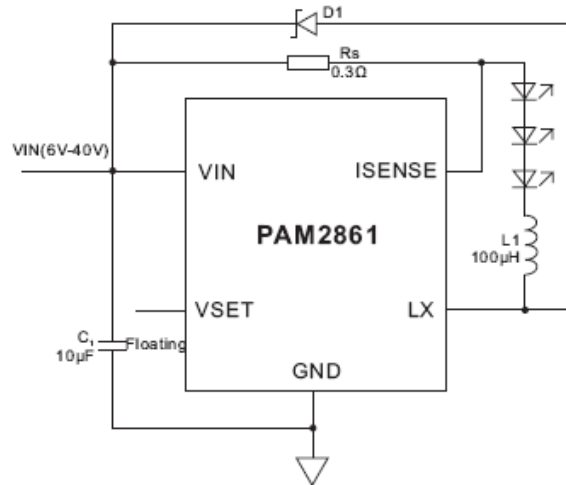
Applications

- Low voltage halogen replacement LEDs
- Low voltage industrial lightings
- LED back-side lightings
- Illuminated signs

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

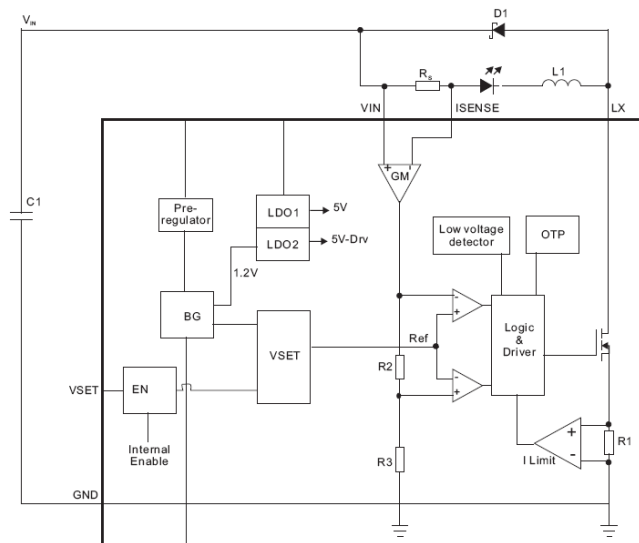
Typical Applications Circuit



Pin Descriptions

Pin Number	Pin Name	Function
1	LX	Drain of NDMOS switch.
2	GND	Ground (0V)
3	VSET	- Multi-function On/Off and brightness control pin: - Leave floating for normal operation. - Drive to voltage below 0.2V to turn off output current - Drive with DC voltage ($0.3V < VSET < 2.5V$) to adjust output current from 12% to 100% of I_{OUTnom} - Drive with PWM signal from open-collector or open-drain transistor, to adjust output current. Adjustment range 1% to 100% of I_{OUTnom} for $f < 500Hz$ - Connect a capacitor from this pin to ground to increase soft-start time. (Default soft-start time = 0.1ms. Additional soft-start time is approx. 1.5ms/1nF)
4	ISENSE	Connect resistor R_S from this pin to VIN to define nominal average output current $I_{OUTnom} = 0.1/R_S$
5	VIN	Input voltage (6V to 40V). Decouple to ground with 10µF or higher X7R ceramic capacitor close to device.

Functional Block Diagram



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for prolonged time periods can affect device reliability. All voltages are with respect to ground.

Parameter	Rating	Unit
Input Voltage Range	-0.3 to +40	V
LX, ISENSE Pin Voltage	-0.3 to +40	
VSET Pin Voltage	-0.3 to +6.0	
Maximum Junction Temperature	170	°C
Storage Temperature	-65 to +170	
Soldering Temperature	300, 5sec	

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

Parameter	Rating	Unit
Input Voltage Range	6 to 40	V
Ambient Temperature Range	-40 to +85	°C
Junction Temperature Range	-40 to +150	°C

Thermal Information

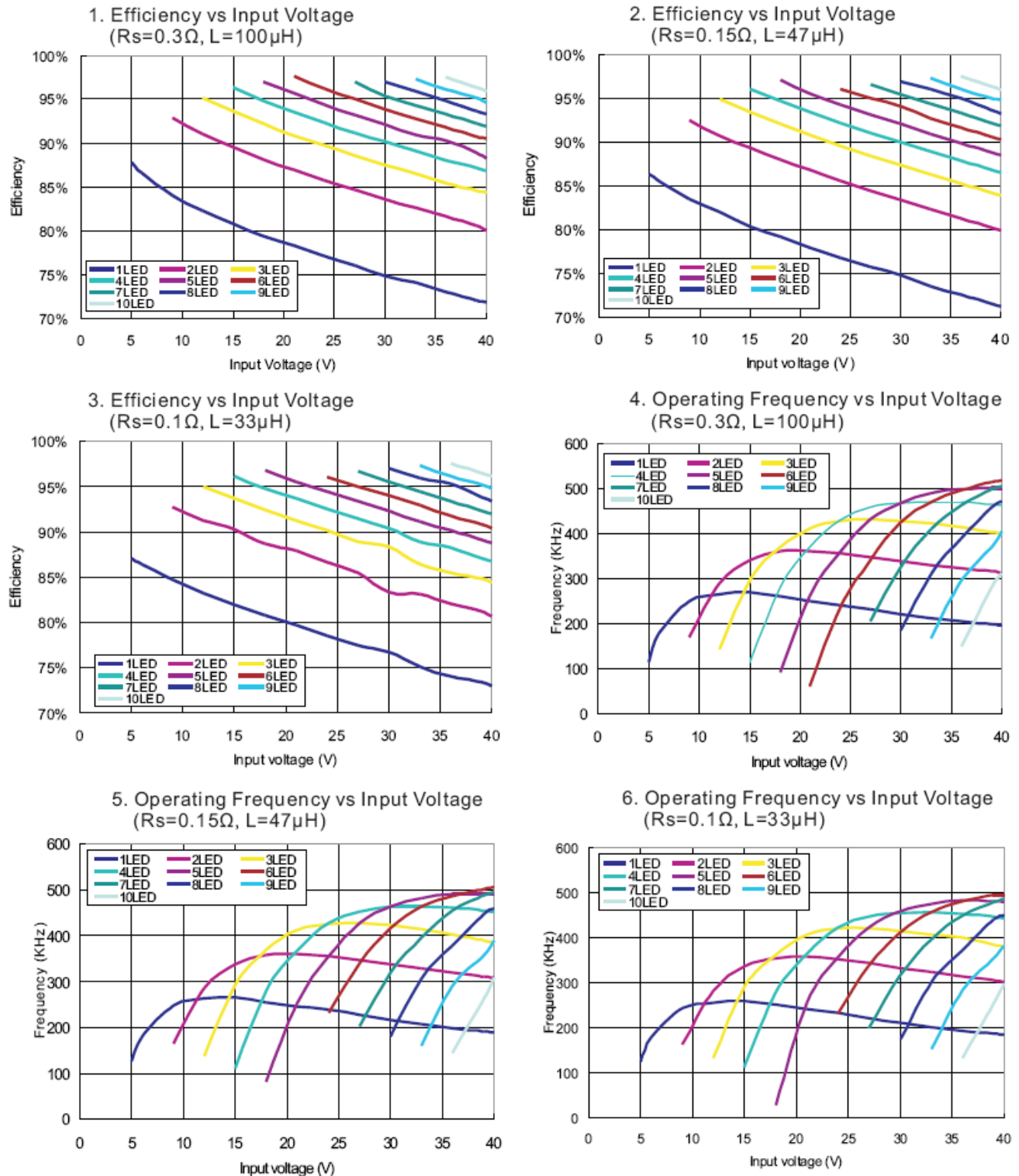
Parameter	Package	Symbol	Max	Unit
Thermal Resistance (Junction to Ambient)	TSOT25	θ_{JA}	250	°C/W
	SOT89-5		160	
Thermal Resistance (Junction to Case)	TSOT25	θ_{JC}	130	
	SOT89-5		45	

Electrical Characteristics (@T_A = +25°C, V_{IN} = 16V, unless otherwise specified.)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Voltage	V _{IN}	—	6	—	40	V
Output Current	I _{LED}	R _S = 0.3Ω	—	333	—	mA
		R _S = 0.1Ω	—	1	—	A
Shutdown Current	I _{SD}	VSET Pin Grouded	—	20	40	μA
Quiescent Current without Switching	I _Q	VSET Pin Floating, V _{IN} = 16V	—	0.6	—	mA
Mean Current Sense Threshold Voltage	V _{SENSE}	Measured on I _{SENSE} Pin with Respect to V _{IN}	95	100	105	mV
Sense Threshold Hysteresis	V _{SENSE_HYS}	—	—	±13	—	%
I _{SENSE} Pin Input Current	I _{SENSE}	V _{SENSE} = V _{IN} - 0.1	—	8	—	μA
VSET Range on VSET Pin	V _{EN}	For DC Dimming	0.3	—	2.5	V
DC Voltage on VSET Pin to Enable	V _{EN(ON)}	V _{EN} Rising	—	0.25	—	V
DC Voltage on VSET Pin to Disable	V _{EN(OFF)}	V _{EN} Falling	—	0.2	—	V
LX Switch On Resistance	R _{LX}	@I _{LX} = 100mA	—	0.3	—	Ω
LX Switch Leakage Current	I _{LX(LEAK)}	—	—	—	5	μA
Soft Start Time	T _{SS}	V _{IN} = 16V, C _{EN} = 1nF	—	1.5	—	ms
Operating Frequency	F _{LX}	V _I = 16V, V _O = 9.6V (3 LEDs) L = 47μF, ΔI = 0.25A (I _{LED} = 1A)	—	233	—	kHz
Recommended Minimum Switch ON Time	T _{ON_REC}	For 4% Accuracy	—	500	—	Ns
Recommended Maximum Switch Frequency	F _{LX(MAX)}	—	—	—	1.0	MHz
Max Duty Circle	—	—	—	98	—	%
Recommended Duty Cycle Range	D _{LX}	—	25	—	75	%
Internal Comparator Propagation Delay (Note 4)	T _{PD}	—	—	45	—	ns
Over Temperature Protection	T _{OTP}	—	—	150	—	°C
Temp Protection Hysteresis	T _{OTP_HYS}	—	—	40	—	°C
Current Limit	I _{XL(MAX)}	Peak Inductor Current	1.5	—	—	A

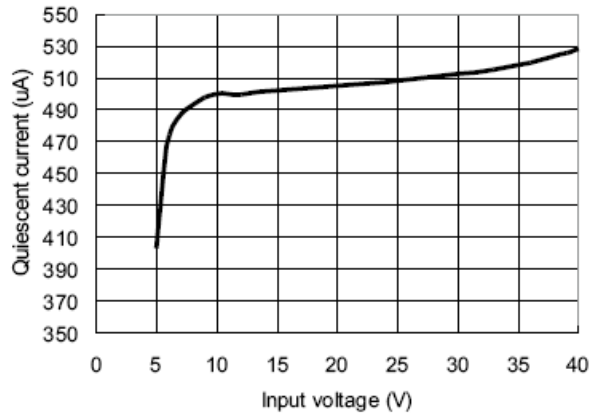
Note: 4. Parameters are not tested at production, but guaranteed by design.

Typical Performance Characteristics (@ $T_A = +25^\circ\text{C}$, $V_{IN} = 16\text{V}$, unless otherwise specified.)

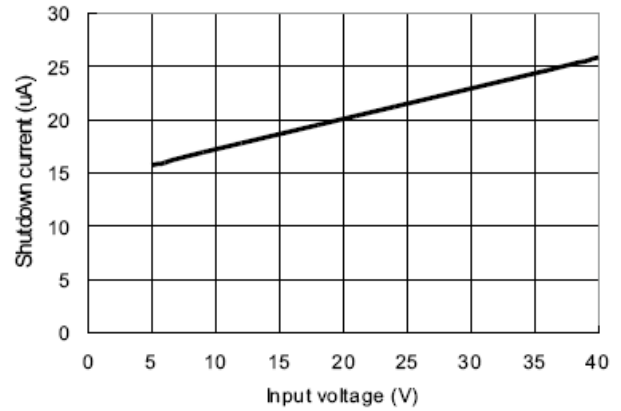


Typical Performance Characteristics (continued) (@ $T_A = +25^\circ\text{C}$, $V_{IN} = 16\text{V}$, unless otherwise specified.)

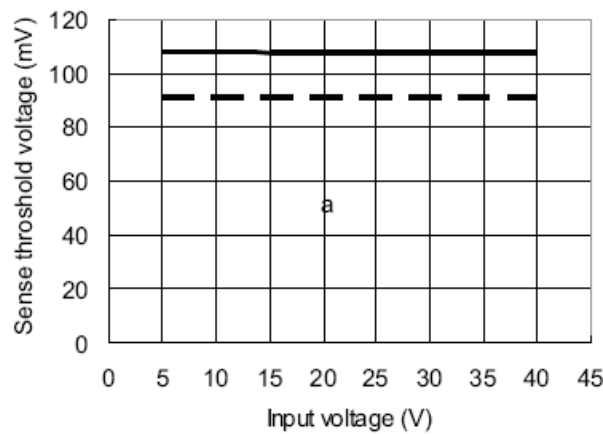
7. Quiescent Current VS. Input Voltage



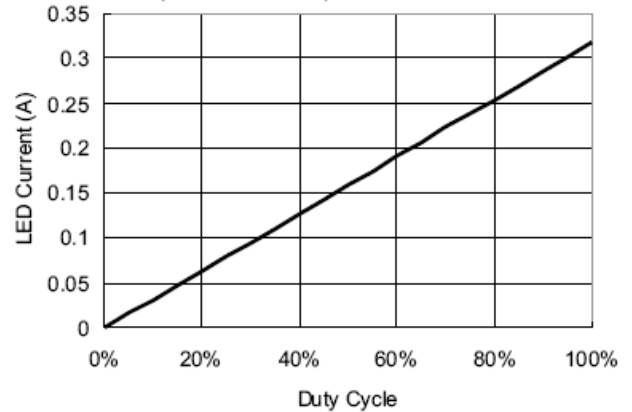
8. Shutdown Current VS. Input Voltage



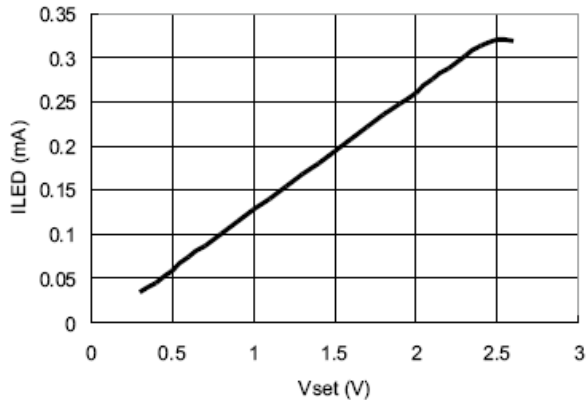
9. Feedback Voltage VS V_{in}



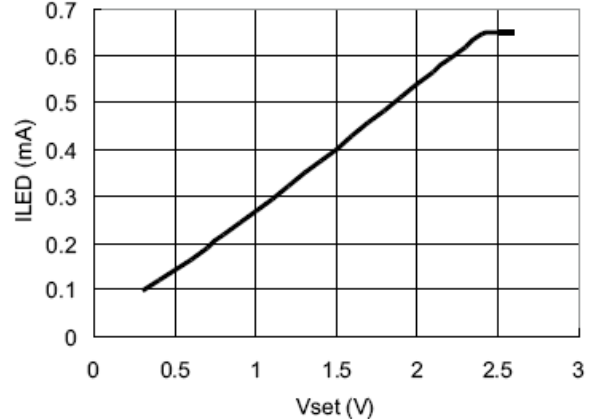
10. Duty Cycle VS LED Current (PWM=200Hz)



11. I_{LED} VS V_{SET}
($V_{IN}=16\text{V}$, 3 LEDs, $100\mu\text{H}$, $R_s=0.3\Omega$)



12. I_{LED} VS V_{SET}
($V_{IN}=16\text{V}$, 3 LEDs, $47\mu\text{H}$, $R_s=0.15\Omega$)

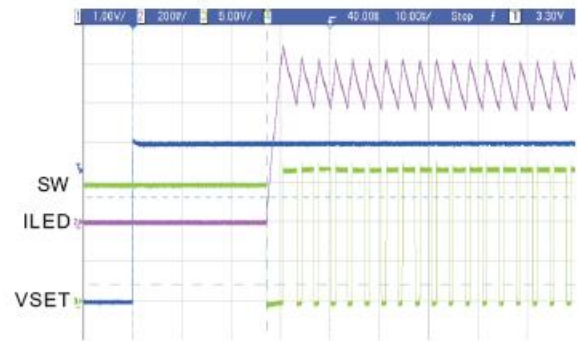


Typical Performance Characteristics (continued) (@T_A = +25°C, C_{IN} = 10μF, C_O = 10μF, L = 4.7μH, unless otherwise specified.)

13. Steady State Waveforms



14. Start up Waveforms



15. Dimming Waveforms (PWM=50%)



16. Pulse skip mode



Application Information

Setting Nominal Average Output Current with External Resistor R_S

The nominal average output current in the LED(s) is determined by the value of the external current sense resistor (R_S) connected between VIN and ISENSE and is given by:

$$I_{OUT(NOM)} = \frac{0.1}{R_S}$$

The table below gives values of nominal average output current for several preferred values of current setting resistor (R_S) in the typical application circuit shown on page 1.

R_S (Ω)	Nominal Average Output Current (mA)
0.1	1000
0.13	760
0.15	667
0.3	333

The above values assume that the VSET pin is floating and at a nominal voltage of VREF (1.25V). Note that $R_S = 0.1\Omega$ is the minimum allowed value of sense resistor under these conditions to maintain switch current below the specified maximum value. It is possible to use different values of R_S if the VSET pin is driven from an external voltage.

Capacitor Selection

A low ESR capacitor should be used for input decoupling, as the ESR of this capacitor appears in series with the supply source impedance and lowers overall efficiency. This capacitor has to supply the relatively high peak current to the coil and smooth the current ripple on the input supply. A minimum value of 4.7 μ F is acceptable if the input source is close to the device, but higher values will improve performance at lower input voltages, especially when the source impedance is high. The input capacitor should be placed as close as possible to the IC.

For maximum stability over temperature and voltage, capacitors with X7R, X5R, or better dielectric are recommended. Capacitors with Y5V dielectric are not suitable for decoupling in this application and should NOT be used.

Inductor Selection

Recommended inductor values for the PAM2861 are in the range 33 μ H to 100 μ H. Higher values of inductance are recommended at higher supply voltages in order to minimize errors due to switching delays, which in increased ripple and lower efficiency. Higher values of inductance also result in a smaller change in output current over the supply voltage range. The inductor should be mounted as close to the device as possible with low resistance connections to the LX and VIN pins. The chosen coil should have a saturation current higher than the peak output current and a continuous current rating above the required mean output current.

The inductor value should be chosen to maintain operating duty cycle and switch 'on'/'off' times within the specified limits over the supply voltage and load current range. The following equations can be used as a guide.

LX Switch 'On' time

$$T_{ON} = \frac{L \Delta I}{V_{IN} - V_{LED} - I_{LED}(R_S + R_L + R_{LX})}$$

Lx Switch 'Off' time

$$T_{OFF} = \frac{L \Delta I}{V_{LED} + V_D + I_{LED}(R_S + R_L)}$$

Where: L is the coil inductance; R_L is the coil resistance; R_S is the current sense resistance; I_{LED} is the required LED current; ΔI is the coil peak-peak ripple current (Internally set to 0.25 x I_{LED}); V_{IN} is the supply voltage; V_{LED} is the total LED forward voltage; R_{LX} is the switch resistance (0.3 Ω nominal); V_D is the diode forward voltage at the required load current.

Application Information (continued)

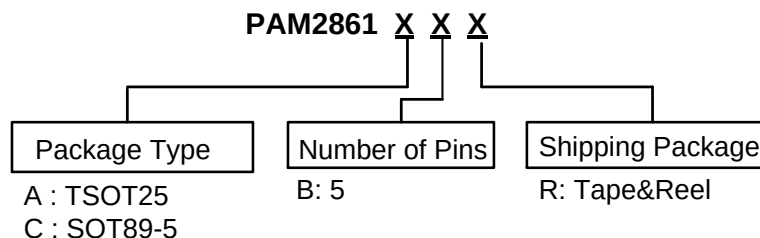
Diode Selection

For maximum efficiency and performance, the rectifier (D1) should be a fast low capacitance Schottky diode with low reverse leakage at the maximum operating voltage and temperature. They also provide better efficiency than silicon diodes, due to a combination of lower forward voltage and reduced recovery time.

It is important to select parts with a peak current rating above the peak coil current and a continuous current rating higher than the maximum output load current. It is very important to consider the reverse leakage of the diode when operating above +85°C. Excess leakage will increase the power dissipation in the device and if close to the load may create a thermal runaway condition.

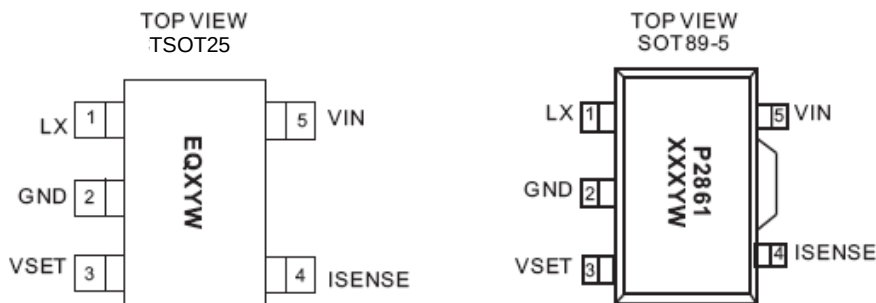
The higher forward voltage and overshoot due to reverse recovery time in silicon diodes will increase the peak voltage on the LX output. If a silicon diode is used, care should be taken to ensure that the total voltage appearing on the LX pin including supply ripple, does not exceed the specified maximum value.

Ordering Information



Part Number	Marking Code	Package	Packing	
			Qty.	Carrier
PAM2861ABR	EQXYW	TSOT25	3000 Units	Tape & Reel
PAM2861CBR	P2861 XXXYW	SOT89-5	1000 Units	Tape & Reel

Marking Information

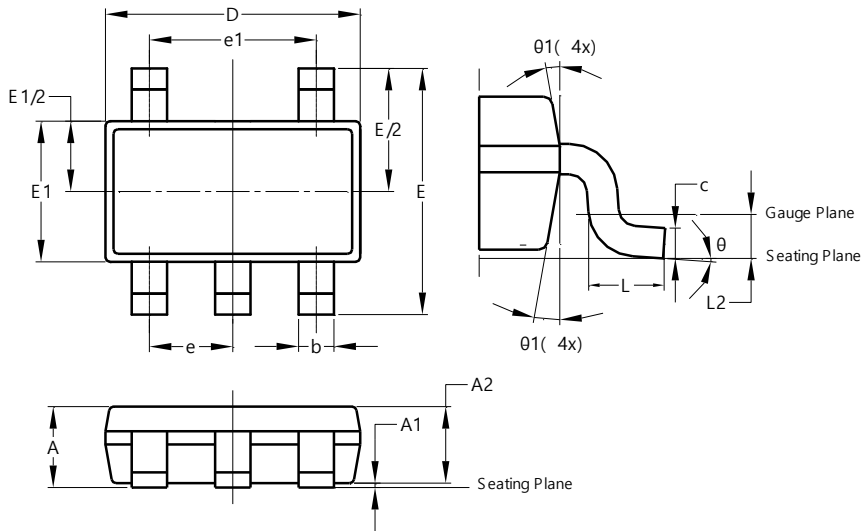


EQ: Product Code of
 PAM2861
 X: Internal Code
 Y: Year
 W: Week

Package Outline Dimensions

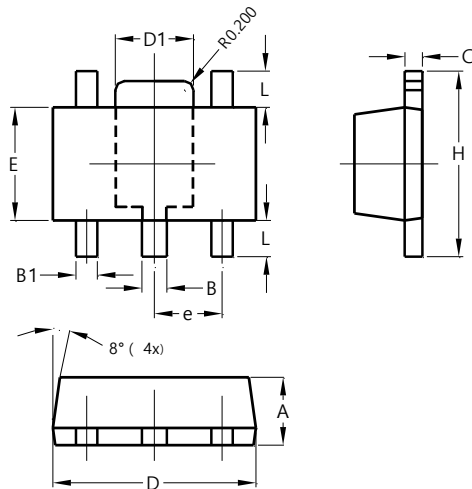
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

Package 1: TSOT25



TSOT25			
Dim	Min	Max	Typ
A	-	1.00	-
A1	0.01	0.10	-
A2	0.84	0.90	-
b	0.30	0.45	-
c	0.12	0.20	-
D	-	-	2.90
E	-	-	2.80
E1	-	-	1.60
e	0.95 BSC		
e1	1.90 BSC		
L	0.30	0.50	-
L2	0.25 BSC		
θ	0°	8°	4°
θ1	4°	12°	-
All Dimensions in mm			

Package 2: SOT89-5

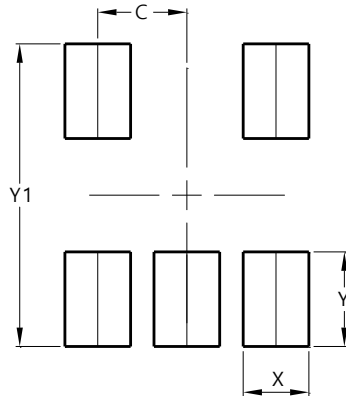


SOT89-5			
Dim	Min	Max	Typ
A	1.40	1.60	1.50
B	0.50	0.62	0.56
B1	0.44	0.54	0.48
C	0.35	0.43	0.38
D	4.40	4.60	4.50
D1	1.62	1.83	1.733
E	2.40	2.60	2.50
e	-	-	1.50
H	3.95	4.25	4.10
L	0.65	0.95	0.80
All Dimensions in mm			

Suggested Pad Layout

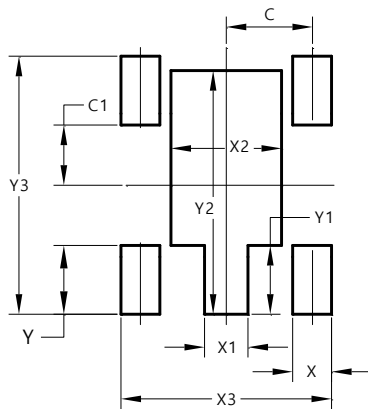
Please see <http://www.diodes.com/package-outlines.html> for the latest version.

Package 1: TSOT25



Dimensions	Value (in mm)
C	0.950
X	0.700
Y	1.000
Y1	3.199

Package 2: SOT89-5



Dimensions	Value (in mm)
C	1.500
C1	1.050
X	0.680
X1	0.760
X2	1.930
X3	3.680
Y	1.200
Y1	1.200
Y2	4.250
Y3	4.500

Mechanical Data

TSOT25 Package

Moisture Sensitivity: MSL3 per JESD22-A113

Terminals: Finish – Matte Tin Plated Leads, Solderable per M2003 JESD22-B102^(e3)

Weight: 0.013 grams (Approximate)

SOT89-5 Package

Moisture Sensitivity: MSL3 per JESD22-A113

Terminals: Finish – Matte Tin Plated Leads, Solderable per M2003 JESD22-B102^(e3)

Weight: 0.081 grams (Approximate)

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